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FDB14N30

N-Channel UniFET™ MOSFET

300 V, 14 A, 290 mΩ

Features

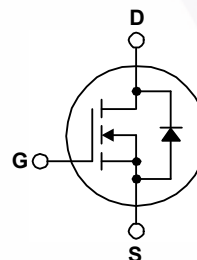
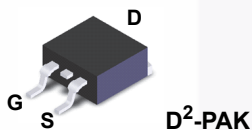
- $R_{DS(on)} = 290 \text{ m}\Omega$ (Max.) @ $V_{GS} = 10 \text{ V}$, $I_D = 7 \text{ A}$
- Low Gate Charge (Typ. 18 nC)
- Low C_{rss} (Typ. 17 pF)
- 100% Avalanche Tested
- Improved dv/dt Capability

Applications

- Lighting
- Uninterruptible Power Supply
- AC-DC Power Supply

Description

UniFET™ MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.



Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted.

| Symbol | Parameter | | FDB14N30TM | Unit |
|----------------|--|--|-------------|---------------------|
| V_{DSS} | Drain-Source Voltage | | 300 | V |
| I_D | Drain Current | - Continuous ($T_C = 25^\circ\text{C}$) | 14 | A |
| | | - Continuous ($T_C = 100^\circ\text{C}$) | 8.4 | A |
| I_{DM} | Drain Current | - Pulsed (Note 1) | 56 | A |
| V_{GSS} | Gate-Source voltage | | ± 30 | V |
| E_{AS} | Single Pulsed Avalanche Energy (Note 2) | | 330 | mJ |
| I_{AR} | Avalanche Current (Note 1) | | 14 | A |
| E_{AR} | Repetitive Avalanche Energy (Note 1) | | 14 | mJ |
| dv/dt | Peak Diode Recovery dv/dt (Note 3) | | 4.5 | V/ns |
| P_D | Power Dissipation | ($T_C = 25^\circ\text{C}$) | 140 | W |
| | | - Derate above 25°C | 1.12 | W/ $^\circ\text{C}$ |
| T_J, T_{STG} | Operating and Storage Temperature Range | | -55 to +150 | $^\circ\text{C}$ |
| T_L | Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds | | 300 | $^\circ\text{C}$ |

Thermal Characteristics

| Symbol | Parameter | FDB14N30TM | Unit |
|-----------------|--|------------|---------------------------|
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case, Max | 0.87 | $^\circ\text{C}/\text{W}$ |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient (minimum pad of 2 oz copper), Max. | 62.5 | |
| | Thermal Resistance, Junction to Ambient (1 in ² pad of 2 oz copper), Max. | 40 | |

Package Marking and Ordering Information

| Device Marking | Device | Package | Reel Size | Tape Width | Quantity |
|----------------|------------|---------|-----------|------------|-----------|
| FDB14N30 | FDB14N30TM | D2-PAK | 330mm | 24mm | 800 units |

Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted.

| Symbol | Parameter | Conditions | Min. | Typ. | Max | Unit |
|---|---|--|----------|------|---------|--------------------|
| Off Characteristics | | | | | | |
| BV_{DSS} | Drain-Source Breakdown Voltage | $V_{GS} = 0V, I_D = 250\mu A$ | 300 | -- | -- | V |
| $\frac{\Delta BV_{DSS}}{\Delta T_J}$ | Breakdown Voltage Temperature Coefficient | $I_D = 250\mu A$, Referenced to 25°C | -- | 0.3 | -- | $V/^\circ\text{C}$ |
| I_{DSS} | Zero Gate Voltage Drain Current | $V_{DS} = 300V, V_{GS} = 0V$ $V_{DS} = 240V, T_C = 125^\circ\text{C}$ | -- | -- | 1 10 | μA μA |
| I_{GSSF} | Gate-Body Leakage Current, Forward | $V_{GS} = 30V, V_{DS} = 0V$ | -- | -- | 100 | nA |
| I_{GSSR} | Gate-Body Leakage Current, Reverse | $V_{GS} = -30V, V_{DS} = 0V$ | -- | -- | -100 | nA |
| On Characteristics | | | | | | |
| $V_{GS(th)}$ | Gate Threshold Voltage | $V_{DS} = V_{GS}, I_D = 250\mu A$ | 3.0 | -- | 5.0 | V |
| $R_{DS(on)}$ | Static Drain-Source On-Resistance | $V_{GS} = 10V, I_D = 7A$ | -- | 0.24 | 0.29 | Ω |
| g_{FS} | Forward Transconductance | $V_{DS} = 40V, I_D = 7A$ | -- | 10.5 | -- | S |
| Dynamic Characteristics | | | | | | |
| C_{iss} | Input Capacitance | $V_{DS} = 25V, V_{GS} = 0V,$ $f = 1.0\text{MHz}$ | -- | 815 | 1060 | pF |
| C_{oss} | Output Capacitance | | -- | 150 | 195 | pF |
| C_{rss} | Reverse Transfer Capacitance | | -- | 17 | 25 | pF |
| Switching Characteristics | | | | | | |
| $t_{d(on)}$ | Turn-On Delay Time | $V_{DD} = 150V, I_D = 14A$ $R_G = 25\Omega$ | -- | 20 | 50 | ns |
| t_r | Turn-On Rise Time | | -- | 105 | 120 | ns |
| $t_{d(off)}$ | Turn-Off Delay Time | | -- | 30 | 70 | ns |
| t_f | Turn-Off Fall Time | | (Note 4) | -- | 75 | 160 |
| Q_g | Total Gate Charge | $V_{DS} = 240V, I_D = 14A$ $V_{GS} = 10V$ | -- | 18 | 25 | nC |
| Q_{gs} | Gate-Source Charge | | -- | 4.5 | -- | nC |
| Q_{gd} | Gate-Drain Charge | | (Note 4) | -- | 8 | -- |
| Drain-Source Diode Characteristics and Maximum Ratings | | | | | | |
| I_S | Maximum Continuous Drain-Source Diode Forward Current | | -- | -- | 14 | A |
| I_{SM} | Maximum Pulsed Drain-Source Diode Forward Current | | -- | -- | 56 | A |
| V_{SD} | Drain-Source Diode Forward Voltage | $V_{GS} = 0V, I_S = 14A$ | -- | -- | 1.4 | V |
| t_{rr} | Reverse Recovery Time | $V_{GS} = 0V, I_S = 14A$ $di_F/dt = 100A/\mu s$ | -- | 235 | -- | ns |
| Q_{rr} | Reverse Recovery Charge | | -- | 1.6 | -- | μC |

NOTES:

1. Repetitive Rating: Pulse width limited by maximum junction temperature
2. $L = 2.8\text{mH}, I_{AS} = 14A, V_{DD} = 50V, R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$
3. $I_{SD} \leq 14A, di/dt \leq 200A/\mu s, V_{DD} \leq BV_{DSS}$, Starting $T_J = 25^\circ\text{C}$
4. Essentially Independent of Operating Temperature Typical Characteristics

Typical Characteristics

Figure 1. On-Region Characteristics

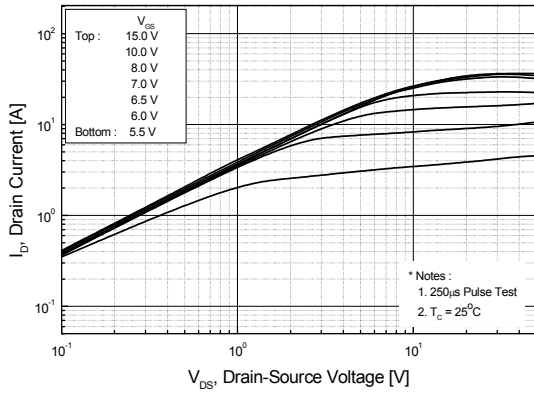


Figure 2. Transfer Characteristics

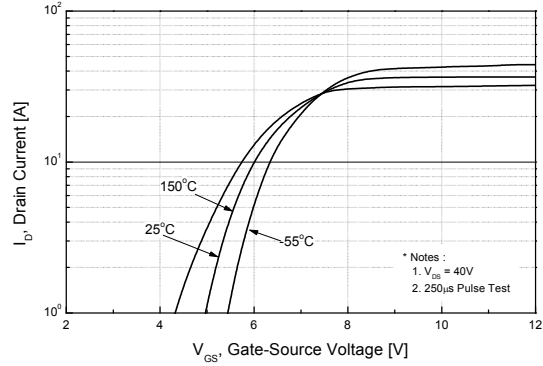


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

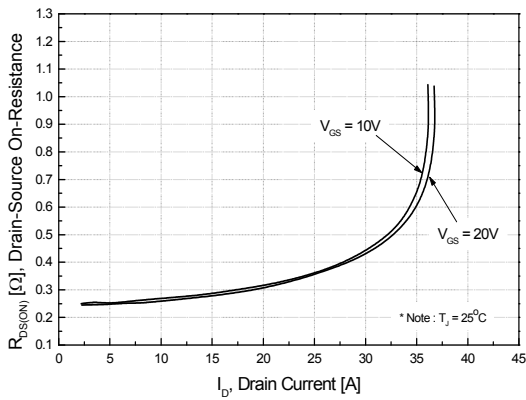


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

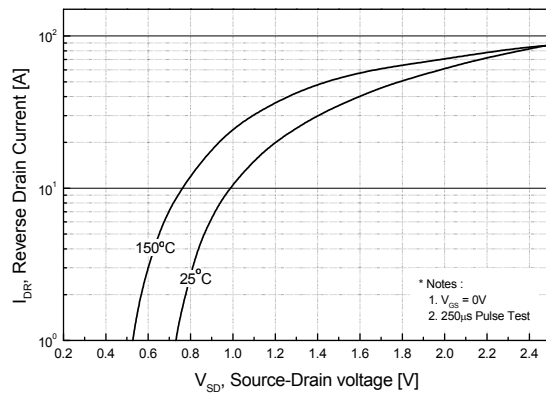


Figure 5. Capacitance Characteristics

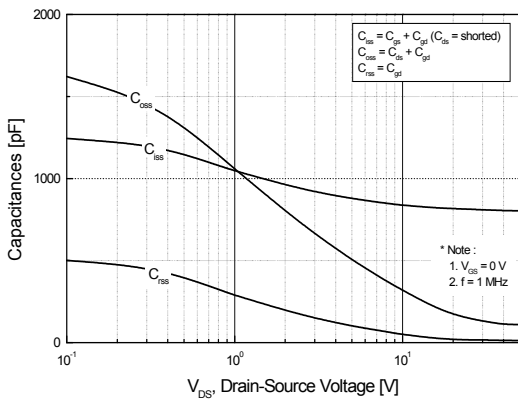
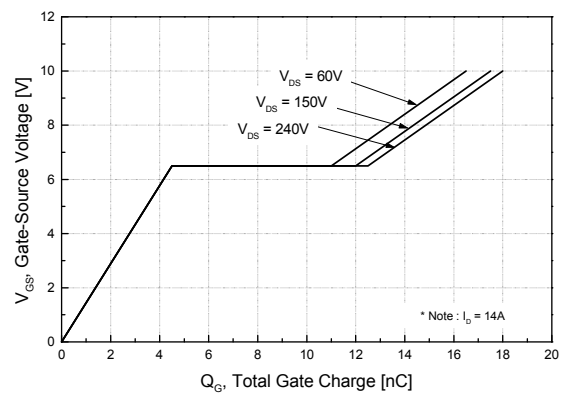


Figure 6. Gate Charge Characteristics



Typical Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

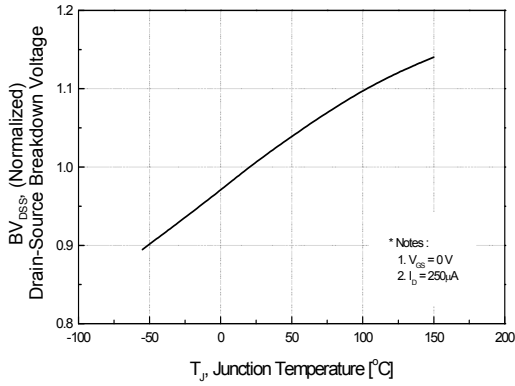


Figure 8. On-Resistance Variation vs. Temperature

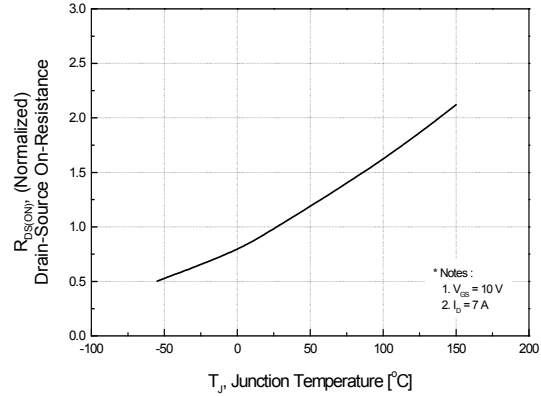


Figure 9. Maximum Safe Operating Area

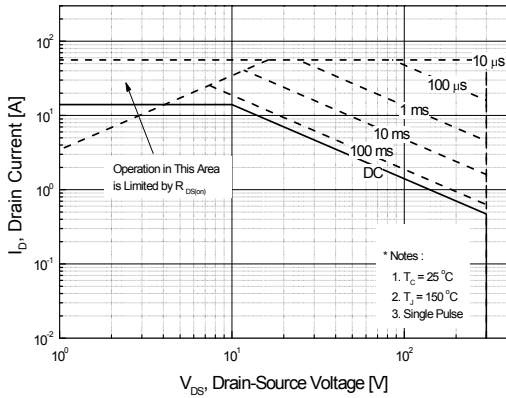


Figure 10. Maximum Drain Current vs. Case Temperature

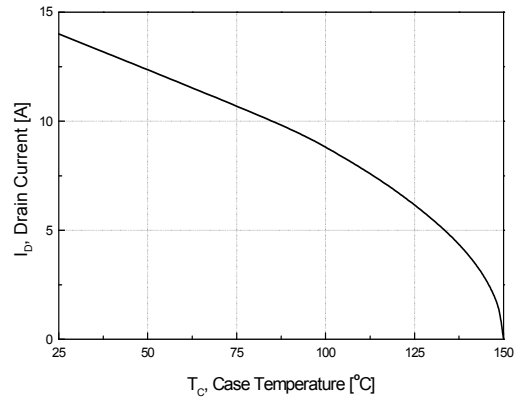


Figure 11. Transient Thermal Response Curve

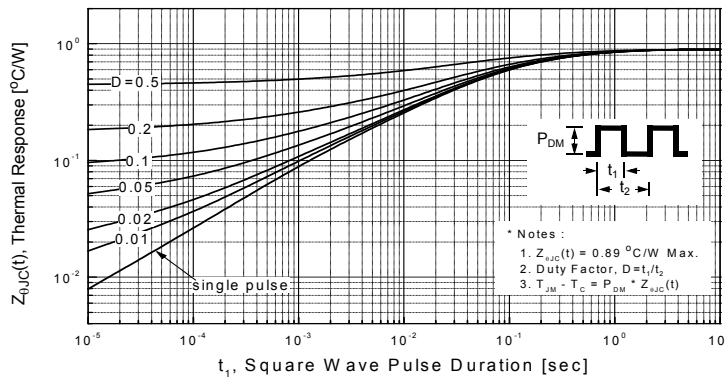


Figure 12. Gate Charge Test Circuit & Waveform

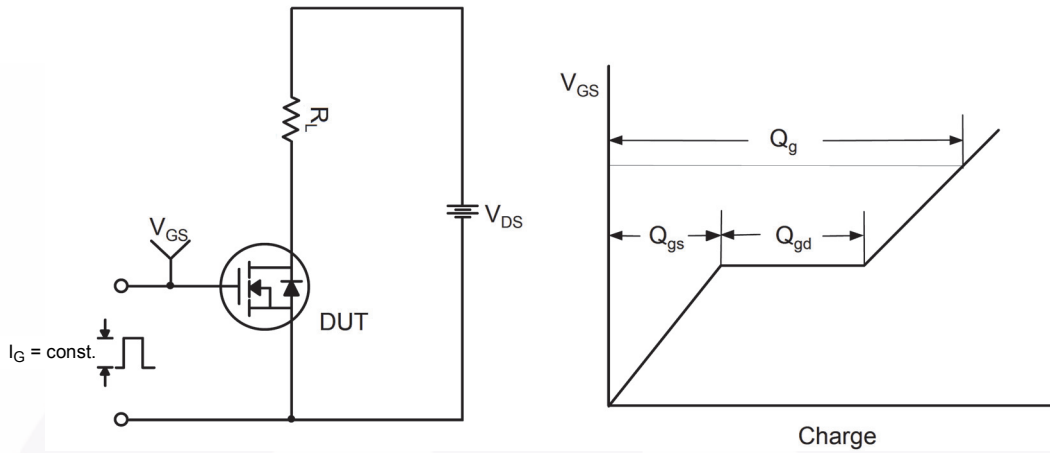


Figure 13. Resistive Switching Test Circuit & Waveforms

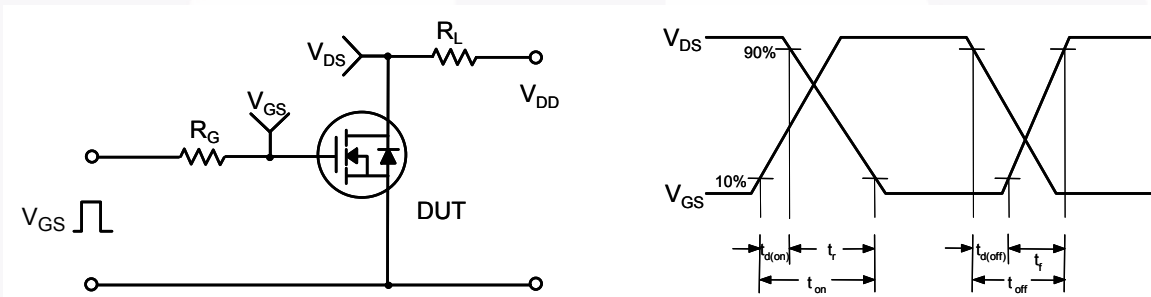


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

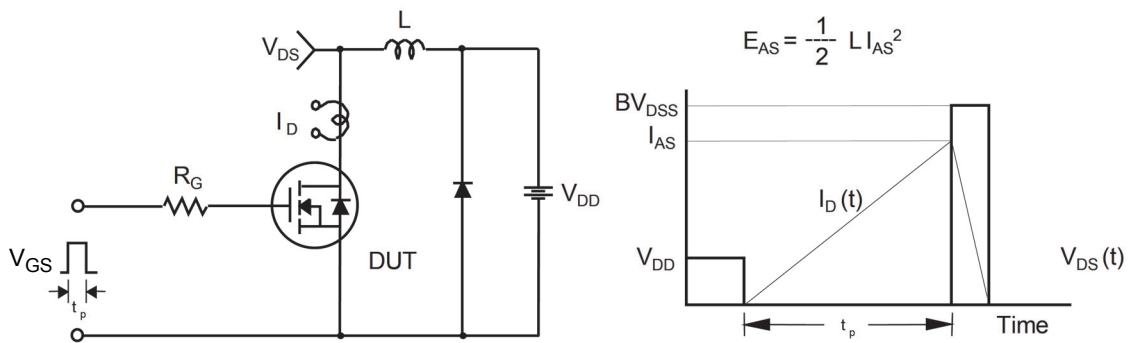
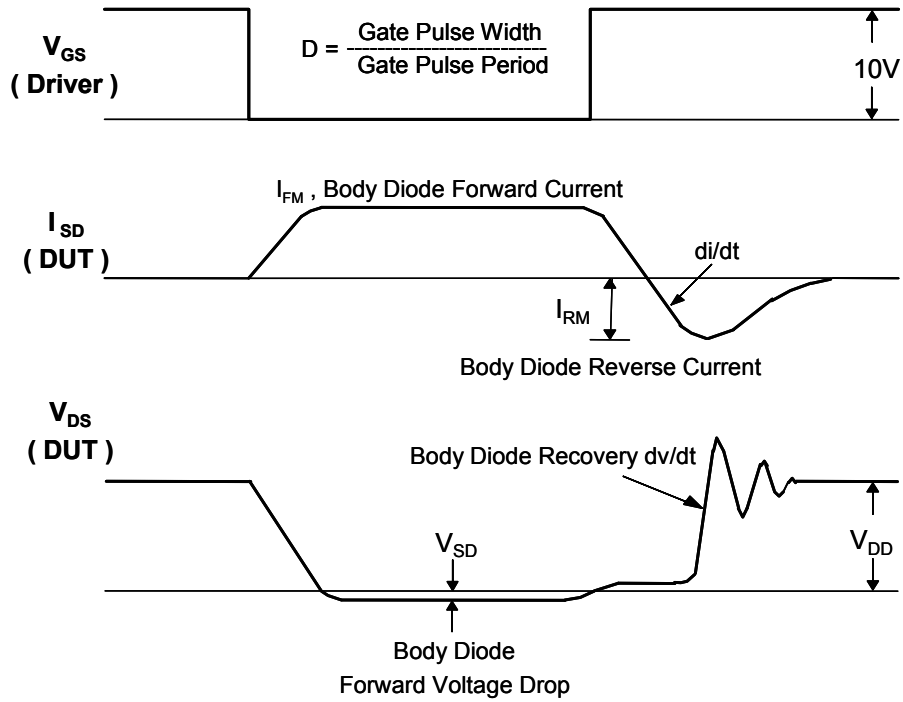


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms



Mechanical Dimensions

TO-263 2L (D²PAK)



Figure 16. 2LD, TO263, Surface Mount

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Dimension in Millimeters



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